

UNISONIC TECHNOLOGIES CO., LTD

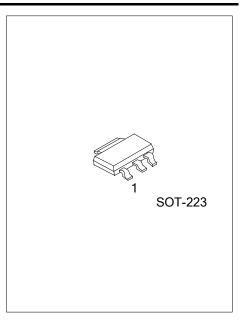
UP1855

PNP SILICON TRANSISTOR

HIGH CURRENT TRANSISTOR

FEATURES

- * High current switching
- * Low $V_{CE(SAT)}$
- * High h_{FE}



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Decking	
			1	2	3	Packing	
UP1855G-x-/	AA3-R	SOT-223	В	С	Е	Tape Reel	
Note: Pin Assignment: E: Emitter B: Base C: Case							
UP1855 <u>G-x-AA3-R</u>	(1)Packing Type (2)Package Type (3)Rank (4)Green Package	(1) R: Tape Re (2) AA3:SOT-2 (3) x: refer to C (4) G: Halogen	23 Iassific				

MARKING



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ABSOLUATE MAXIUM RATINGS (T_A= 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V _{CBO}	-180	V
Collector-Emitter Voltage	V _{CEO}	-140	V
Emitter-Base Voltage	V _{EBO}	-6	V
Peak Pulse Current	Ісм	-10	А
Continuous Collector Current	lc	-4	А
Power Dissipation ($T_a = 25^{\circ}C$) (Note 2)	PD	3	W
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-40 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. The power which can be dissipated assuming the device is mounted in a typical manner on a P.C.B. with copper equal to 4 square inch minimum

ELECTRICAL CHARACTERISTICS (T_A= 25°C, unless otherwise specified)

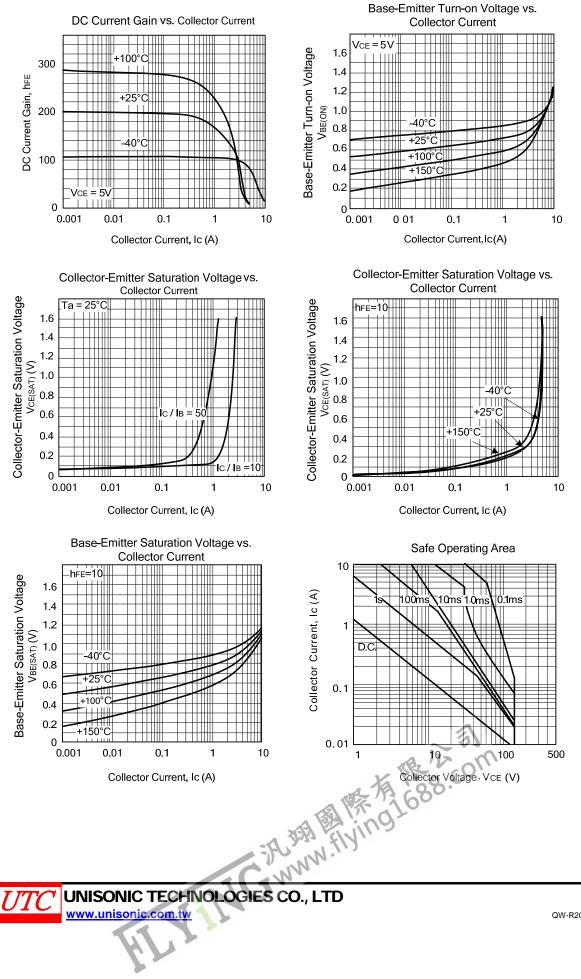
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_{CBO}	I _C = -100μA	-180	-210		V
Collector-Emitter Breakdown Voltage	BV_{CEO}	I _C = -10mA	-140	-170		V
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E = -100μA (Note)	-6	-8		V
Collector Cut-off Current	I _{CBO}	V _{CB} =-150V			-50	nA
		V _{CB} =-150V, T _a =100°C			-1	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} =-6V			-10	nA
Collector-Emitter Saturation Voltage	V _{CE (SAT)}	I _C =-100mA, I _B =-5mA (Note)		-30	-60	mV
		I _C =-500mA, I _B =-50mA (Note)		-70	-120	mV
		I _C =-1A, I _B =-100mA (Note)		-110	-150	mV
		I _C =-3A, I _B =-300mA (Note)		-275	-550	mV
Base-Emitter Saturation Voltage	V _{BE (SAT)}	I _C =-3A, I _B =-300mA (Note)		-970	-1110	mV
Base-Emitter Turn-On Voltage	V _{BE (ON)}	V _{CE} =-5V , I _C =-3A (Note)		-830	-950	mV
DC Current Gain	h _{FE1}	V _{CE} =-5V , I _C =-10mA (Note)	100	200		
	h _{FE2}	V _{CE} =-5V , I _C =-1A (Note)	100		300	
	h _{FE3}	V _{CE} =-5V , I _C =-3A (Note)	28	140		
	h _{FE4}	V _{CE} =-5V , I _C =-10A (Note)		10		
Transition Frequency	f⊤	V _{CE} =-10V , I _C =-100mA, f=50MHz		110		MHz
Output Capacitance	Cob	V _{CB} =-20V, f=1MHz		40		pF
· · ·	t _{ON}	V _{CC} =-50V, I _C =-1A		68		ns
Switching Times	t _{OFF}	I _{B1} =-100mA, I _{B2} =100mA		1030		ns

Note: Pulse test: $t_P \leq 300 \mu s$, Duty cycle $\leq 2\%$

CLASSIFICATION OF h_{FE3}

RANK	A	В
RANGE	28~75	75 (MIN.)

TYPICAL CHARACTERISTICS



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